

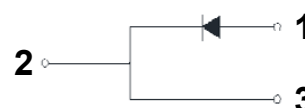


## Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on  $V_F$

## Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway



## Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives



Part Number	Package	Qty(PCS)
HFFSP2065A	TO-220C-2L	50

## Maximum Ratings ( $T_C = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
$V_{RRM}$	Repetitive Peak Reverse Voltage	650	V	
$V_{RSM}$	Surge Peak Reverse Voltage	650	V	
$V_{DC}$	DC Blocking Voltage	650	V	
$I_F$	Continuous Forward Current	20	A	$T_C = 125^\circ\text{C}$
$I_{FRM}$	Repetitive Peak Forward Surge Current	81	A	$T_C = 110^\circ\text{C}$ , $t_p = 10$ ms, Half Sine Wave
$I_{FSM}$	Non-Repetitive Peak Forward Surge Current	123 104	A	$T_C = 25^\circ\text{C}$ , $t_p = 10$ ms, Half Sine Wave $T_C = 150^\circ\text{C}$ , $t_p = 10$ ms, Half Sine Wave
$I_{F,Max}$	Non-Repetitive Peak Forward Surge Current	450	A	$T_C = 25^\circ\text{C}$ , $t_p = 10$ $\mu\text{s}$ , Pulse
$P_{tot}$	Power Dissipation	115	W	$T_C = 25^\circ\text{C}$
$T_J, T_{stg}$	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$	



## Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions
$V_F$	Forward Voltage	1.35 1.5	1.5 -	V	$I_F = 20\text{ A}, T_J = 25^\circ\text{C}$ $I_F = 20\text{ A}, T_J = 175^\circ\text{C}$
$I_R$	Reverse Current	0.06 12	100 -	$\mu\text{A}$	$V_R = 650\text{ V}, T_J = 25^\circ\text{C}$ $V_R = 650\text{ V}, T_J = 175^\circ\text{C}$
$Q_C$	Total Capacitive Charge	24		nC	$V_R = 400\text{ V}, I_F = 10\text{ A}$ $di/dt = 500\text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$
C	Total Capacitance	1000 91		pF	$V_R = 0\text{ V}, T_J = 25^\circ\text{C}, f = 1\text{ MHz}$ $V_R = 400\text{ V}, T_J = 25^\circ\text{C}, f = 1\text{ MHz}$
$E_{\text{ava}}$	Non-repetitive Avaranche Energy	220		mJ	$L=1\text{mH}$

Note: This is a majority carrier diode, so there is no reverse recovery charge.

## Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{JC}^\theta$	Thermal Resistance from Junction to Case	0.87	$^\circ\text{C}/\text{W}$

## Typical Performance

Fig.1  $V_F - I_F$  Characteristics

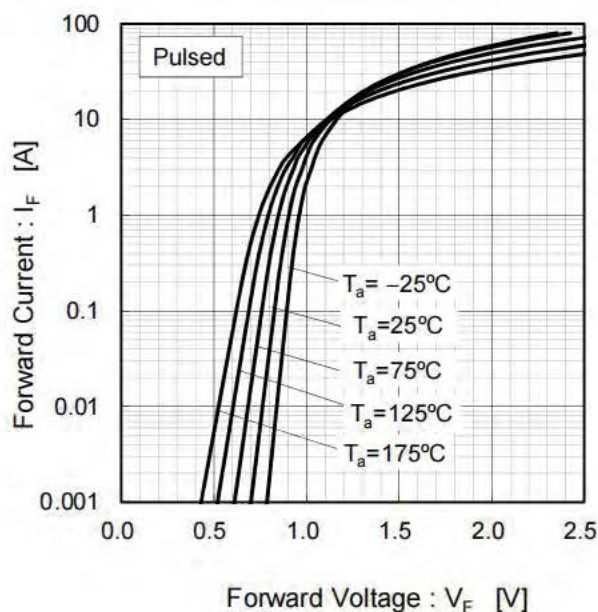
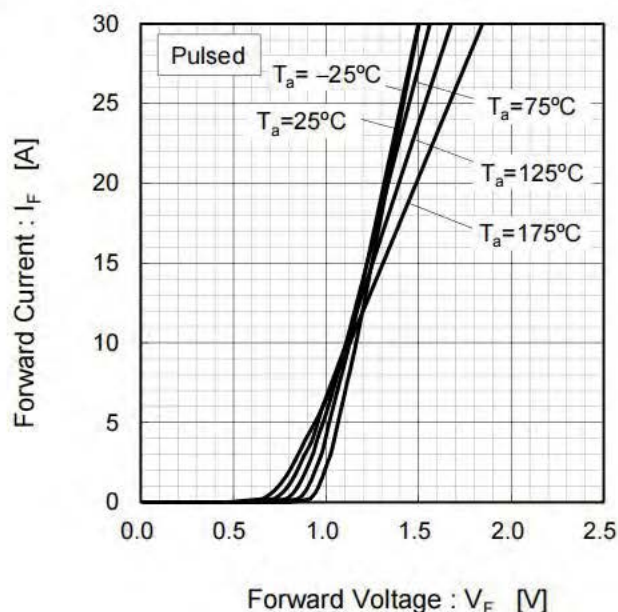


Fig.2  $V_F - I_F$  Characteristics





## Typical Performance

Fig.3  $V_R - I_R$  Characteristics

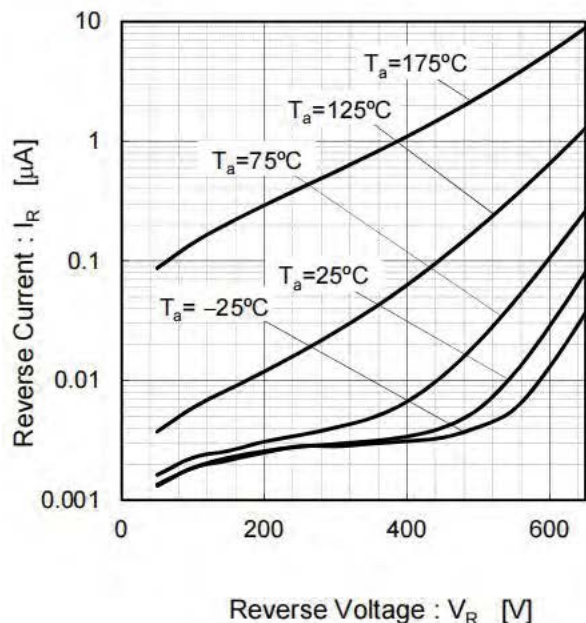


Fig.4  $V_R - C_t$  Characteristics

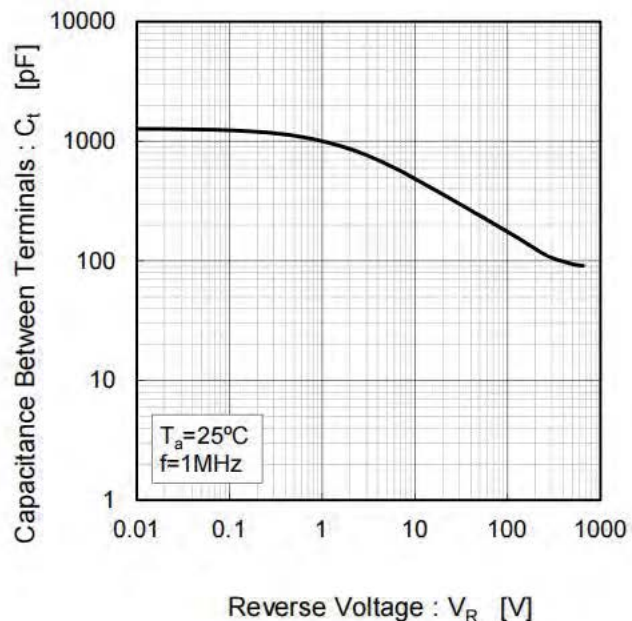


Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

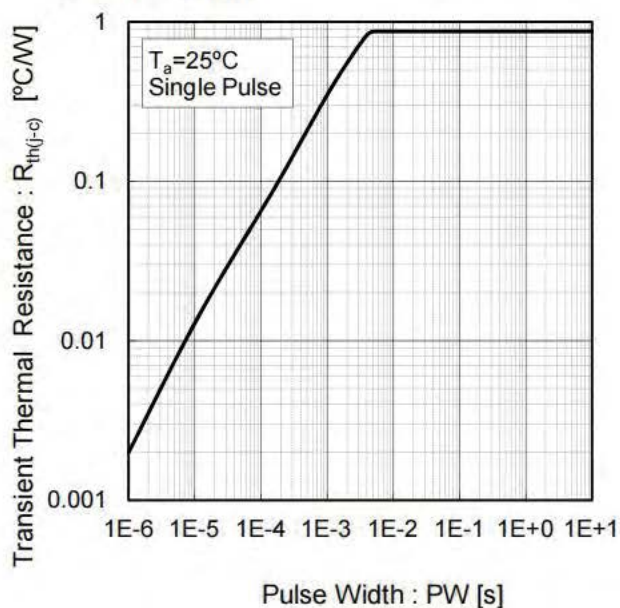
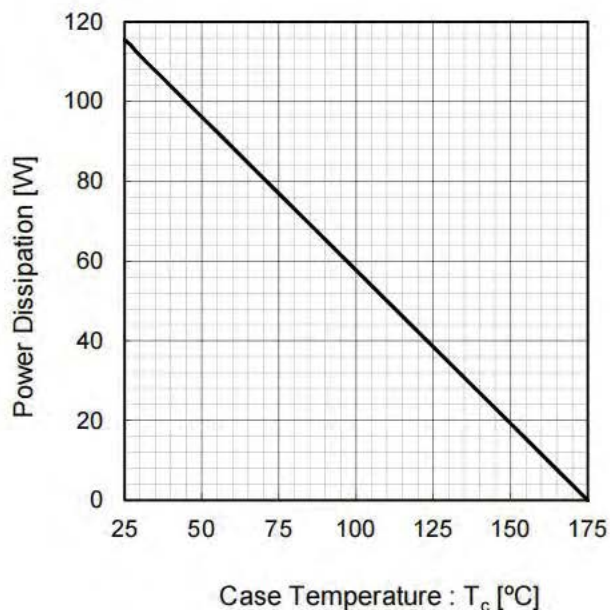


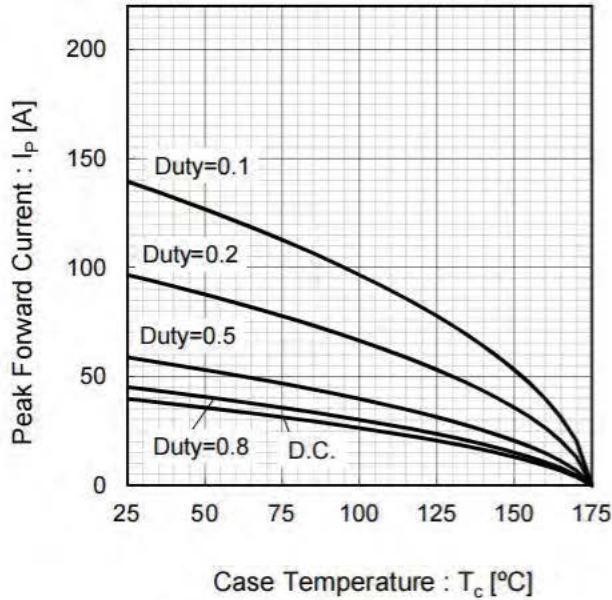
Fig.6 Power Dissipation





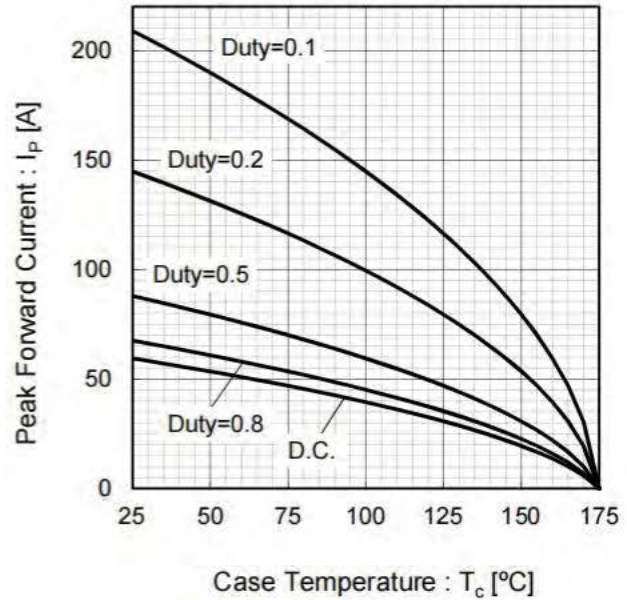
## Typical Performance

Fig.7\*3 Maximum peak forward current derating curve  $I_P - T_c$



\*3 Based on max  $V_f$ , max  $R_{th(j-c)}$   
Valid for switching of above 10kHz,  
excluding D.C. curve.

Fig.8\*4 Typical peak forward current derating curve  $I_P - T_c$  (Not guaranteed)



\*4 Based on typ  $V_f$ , typ  $R_{th(j-c)}$   
Typical value, not guaranteed  
Valid for switching of above 10kHz,  
excluding D.C. curve

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

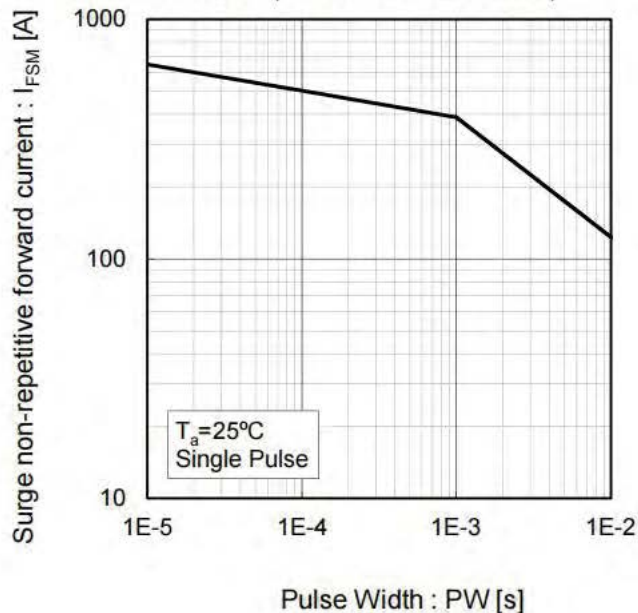
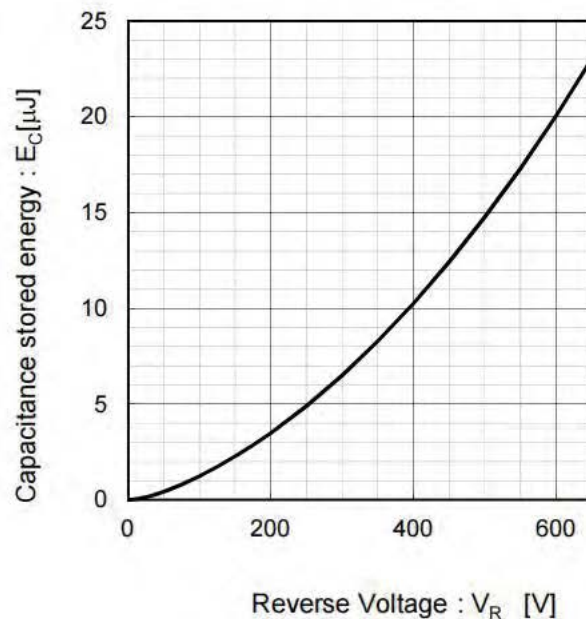


Fig.10 Typical capacitance store energy

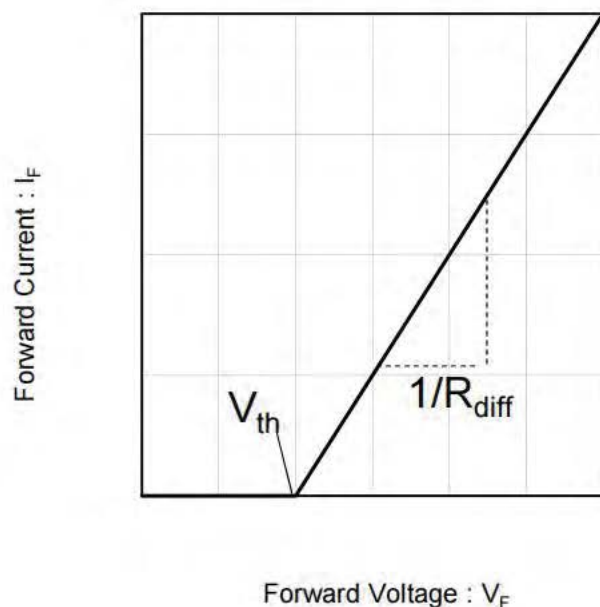






## Typical Performance

Fig.11 Equivalent forward current curve



$$V_F = V_{th} + R_{diff} I_F$$

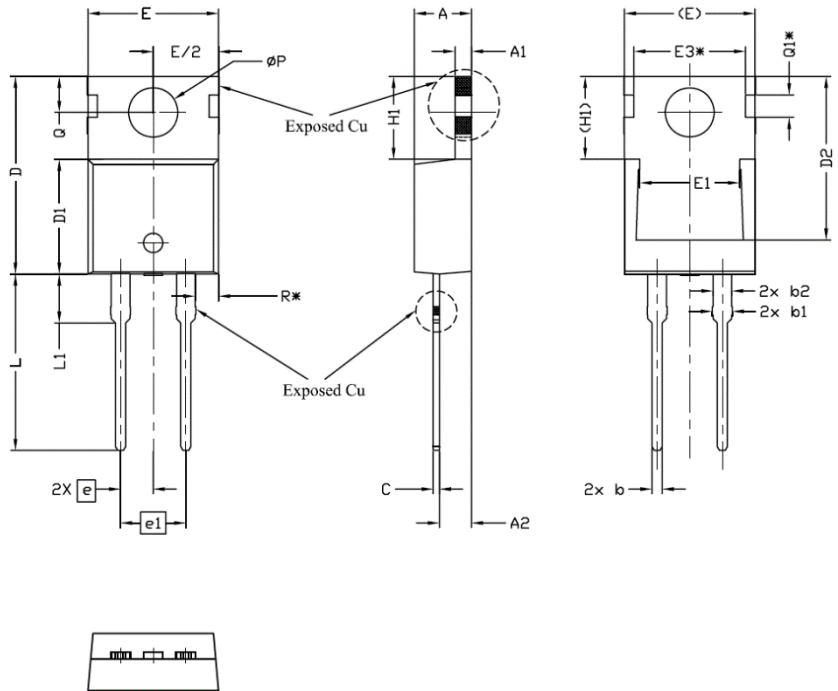
$$V_{th}(T_j) = a_0 + a_1 T_j$$
$$R_{diff}(T_j) = b_0 + b_1 T_j + b_2 T_j^2$$

Symbol	Typical Value	Unit
$a_0$	9.66E-01	V
$a_1$	- 1.10E-03	V/°C
$b_0$	1.76E-02	$\Omega$
$b_1$	3.73E-05	$\Omega/^\circ\text{C}$
$b_2$	3.84E-07	$\Omega/^\circ\text{C}^2$

$T_j$  in °C; -55 °C <  $T_j$  < 175°C ;  $I_F$  < 40A

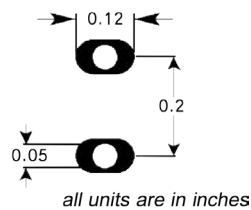


## Package Information TO-220C-2L



SYMBOL	DIMENSIONS			NOTES
	MIN.	NOM.	MAX.	
A	4,24	4,44	4,64	
A1	1.15	1.27	1.40	
A2	2.30	2,48	2,70	
b	0.70	0.80	0.90	
b1	1.20	1,55	1,75	
b2	1,20	1,45	1,70	
c	0.40	0.50	0.60	
D	14,70	15,37	16,00	4
D1	8,82	8,92	9,02	
D2	12,43	12,73	12,83	5
E	9,96	10,16	10,36	4,5
E1	6,86	7,77	8,89	5
E3*	8,70REF.			
e	2,54BSC			
e1	5,08BSC			
H1	6,30	6,45	6,60	5,6
L	13,47	13,72	13,97	
L1	3,60	3,80	4,00	
ØP	3,75	3,84	3,93	
Q	2,60	2,80	3,00	
Q1*	1,73REF.			
R*	1,82REF.			

## Recommended Solder Pad Layout



TO220-2L



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